



## Transistors

### ●Absolute maximum ratings (Ta=25°C)

| Parameter            |               | Symbol                | Limits      | Unit |
|----------------------|---------------|-----------------------|-------------|------|
| Supply voltage       |               | V <sub>CC</sub>       | 50          | V    |
| Input voltage        |               | V <sub>IN</sub>       | 40          | V    |
|                      |               |                       | -10         |      |
| Output current       |               | I <sub>O</sub>        | 50          | mA   |
| Collector current    |               | I <sub>C (Max.)</sub> | 100         | mA   |
| Power dissipation    | EMH11, UMH11N | P <sub>d</sub>        | 150 (TOTAL) | mW   |
|                      | IMH11A        |                       | 300 (TOTAL) |      |
| Junction temperature |               | T <sub>J</sub>        | 150         | °C   |
| Storage temperature  |               | T <sub>stg</sub>      | -55~+150    | °C   |

\*1 120mW per element must not be exceeded.

\*2 200mW per element must not be exceeded.

### ●Electrical characteristics (Ta=25°C)

| Parameter            | Symbol                         | Min. | Typ. | Max. | Unit | Conditions                                            |
|----------------------|--------------------------------|------|------|------|------|-------------------------------------------------------|
| Input voltage        | V <sub>I (off)</sub>           | —    | —    | 0.5  | V    | V <sub>CC</sub> =5V, I <sub>O</sub> =100μA            |
|                      | V <sub>I (on)</sub>            | 3    | —    | —    |      | V <sub>O</sub> =0.3V, I <sub>O</sub> =10mA            |
| Output voltage       | V <sub>O (on)</sub>            | —    | 0.1  | 0.3  | V    | I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA            |
| Input current        | I <sub>I</sub>                 | —    | —    | 0.88 | mA   | V <sub>I</sub> =5V                                    |
| Output current       | I <sub>O (off)</sub>           | —    | —    | 0.5  | μA   | V <sub>CC</sub> =50V, V <sub>I</sub> =0V              |
| DC current gain      | G <sub>i</sub>                 | 30   | —    | —    | —    | V <sub>O</sub> =5V, I <sub>O</sub> =5mA               |
| Transition frequency | f <sub>T</sub>                 | —    | 250  | —    | MHz  | V <sub>CE</sub> =10mA, I <sub>E</sub> =-5mA, f=100MHz |
| Input resistance     | R <sub>I</sub>                 | 7    | 10   | 13   | kΩ   | —                                                     |
| Resistance ratio     | R <sub>Z</sub> /R <sub>I</sub> | 0.8  | 1    | 1.2  | —    | —                                                     |

\* Transition frequency of the device

### ●Electrical characteristic curves

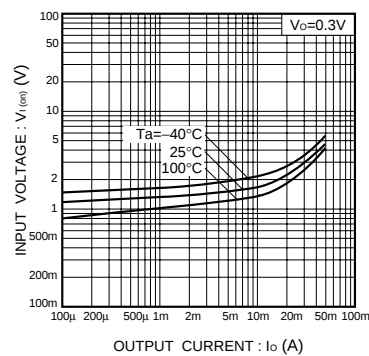


Fig.1 Input voltage vs. output current (ON characteristics)

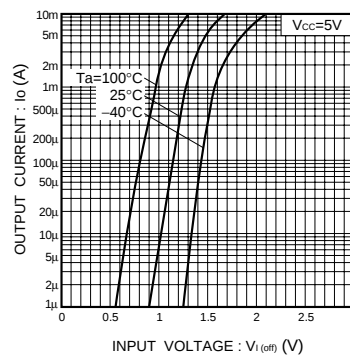


Fig.2 Output current vs. input voltage (OFF characteristics)

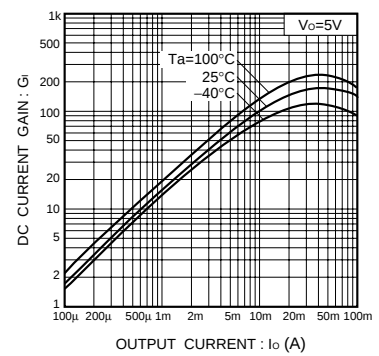


Fig.3 DC current gain vs. output current

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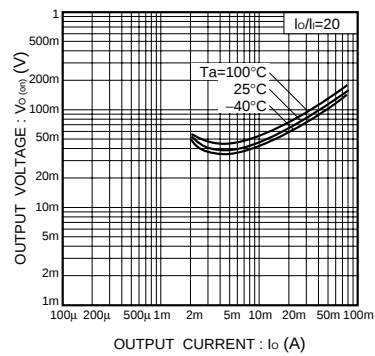


Fig.4 Output voltage vs. output current